D ynam ic nuclear polarization at the edge of a two-dim ensional electron gas

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We have used gated G aA s/A is aA s heterostructures to explore nonlinear transport between spin-resolved Landau level (LL) edge states over a submicron region of two-dimensional electron gas (2D EG). The current I owing from one edge state to the other as a function of the voltage V between them shows diode-like behavior a rapid increase in I above a well-de ned threshold V_t under forward bias, and a slower increase in I under reverse bias. In these measurements, a pronounced in uence of a current-induced nuclear spin polarization on the spin splitting is observed, and supported by a series of NM R experiments. We conclude that the hyper ne interaction plays an important role in determining the electronic properties at the edge of a 2D EG.

I. IN TRODUCTION

The physics of two-dimensional electron gases (2D EG s) form ed at G aA s/A IG aA s hetero junctions has become a very popular eld in the last several years, ow - ing to the 2D EG 'sm any interesting properties, m ost no-tably the quantum Halle ect (QHE) [1]. When placed in a strong perpendicular magnetic eld, the electronic energy levels of the 2D EG congregate into Landau levels (LLs), whose energies are given by:

$$E = (n + \frac{1}{2})h!_{c} + g_{B}BS_{z} + E_{ex} + AhI_{z}iS_{z}$$
(1)

The rst term of Eq. 1 gives the orbital LL splitting, where n is the orbital LL index and h!_c is the cyclotron energy. The second term lifts the spin degeneracy of each orbital LL through the Zeem an interaction for G aAs, g _B B 0.016h!_c, with S_z being the electron spin ($\frac{1}{2}$). The third term expresses the e ects of exchange, which depends sensitively on temperature and on the lling factor = n_sh=eB (the num ber of LLs lled for 2D electron density n_s). Exchange can a ect the total energy considerably, sometimes by as much as a few m eV. The nal term involves the in uence of nuclear polarization hI_z i through the contact hyper ne interaction, the e ect of which is the focus of our paper and is discussed in more detail later.

Due to their high mobility and ease of fabrication, 2DEGs provide a useful medium for examining manybody physicale ects, such as exchange. Even though the Zeem an energy splitting is only a tiny fraction of the orbitalLL splitting, exchange e ects favor a ferrom agnetic ground state near = 1, increasing the e ective spin gap. It has recently been observed that the low-energy excitations of such a spin-polarized 2DEG are not single spin ips, but rather spatially extended spin-textures (skyrm ions), in which electrons gradually tilt their spins from the center of the texture outward, with the size of the skyrm ion set by the competition between exchange and Zeem an energies [2]. Skyrm ions have been detected using various techniques [3,4] in bulk 2D EG s, underscoring the importance of treating the 2D EG as an interacting m any-body system .

It is recognized that the nuclei of the G aAs crystal can a ect the electronic properties of the 2D EG as well. A ny nonzero nuclear polarization $hI_z i$ will create an extra e ective magnetic eld felt by the electrons, producing an O verhauser shift in the electron energies that can be detected with electron spin resonance absorption [5]. In turn, a net electron polarization produces a K night shift in the nuclear energies, which can be used to measure the spin polarization of the 2D EG [3]. In addition to these energy shifts, the hyper ne interaction allows " ip- op" scattering in G aA s, where an electron " ips" its spin simultaneous with the " op" of a nuclear spin in the opposite direction, conserving the net spin of the entire system .

Nuclear spin e ects in bulk 2DEGs have been wellstudied, but in this paper we shall be examining these e ects at the edge of the 2DEG.W hen is an integer, all occupied LLs are full and the bulk 2DEG is incom pressible. At the edge, however, the electron density gradually descends from to zero and the LL energies curve upward, due to the electrostatic con nem ent potential. The intersections of the LLs with the Ferm i energy E_{F} near the edge de ne regions where electrons can be added to the 2DEG. These "edge states" (or "edge channels") are spatially separated independent channels, each carrying an identical amount of current at equilibrium [6]. Self-consistent electrostatic screening modi es the edge states, creating wide compressible and incom pressible stripes at the edge, with a corresponding steplike potential pro le (Fig. 2(a)) [7{11].

The complete many-body physics of the edge is not well understood, although theories predict that the edge m ay exhibit m any-body phenom ena, such as spin textures [12]. The relative tininess of the edge region m akes m any m easurem ent techniques unfeasible, but electronic transport, which necessarily takes place at the edge in the QH regime, provides a probe into the nature of these states. At equilibrium the edge states all maintain the sam e electrochem ical potential. U sing subm icron gates deposited on top of the heterostructure, however, one can selectively backscatter the edge states, induce di erent potentials in di erent edge states, and m easure the resultant inter-edge scattering [13]. Scattering between spin-degenerate [14] and spin-split [15] edge states has been considered previously for the linear regime, as has non-linear scattering between spin-degenerate edge states [10,16]. In this paper, we report m easurem ents of nonlinear transport between spin-split edge states, and show that spin- ip relaxation produces a nuclear polarization of the Ga and As nuclei. This polarization can in turn drastically a ect the electronic energies at the edge of a 2DEG.

In Section II of this paper, we describe the measurem ent setup and the method by which a potential imbalance is created between spin-split edge states using submicron gates. We also describe a simple picture of the edge utilizing the "spin diode" modelused by K ane et al. [17]. Section III contains our experimental results, which display features that are best explained by dynamic nuclear polarization (DNP) of the nuclear spins. We present strong evidence for this interpretation with a series of NMR experiments. We continue in Section IV with some observations about the data, and we brie y discuss some possible consequences of our results for models of the spin-split edge. In Section V we compare our ndings with earlier results by our group [18], and we conclude in Section V I.

II. M EASUREMENT METHODOLOGY

A schem atic diagram of the device under consideration is shown in Fig. 1 (a). E lectrons populated up to an electrochem ical potential = eV enter the two spin-split edge channels from contact 1. G ates A and B ("AB splitgate") are tuned so that the upper (inner, spin-down) edge state is re ected by the gate's potential barrier, but the low er (outer, spin-up) channel is transm itted. A fler passing through these gates, the outer edge channel, still at potential , propagates along gate A in close proxim ity to the grounded inner edge channel. The edge channels are not in equilibrium in this region, so there is a net scattering of electrons from one channel to the other. These scattered electrons propagate in the inner edge channel to a current am pli er (contact 3) and are m easured as current I. Unscattered electrons rem ain in the outer edge channel and pass between gates A and C ("AC split-gate") into the grounded contact 2 and avoid detection by the current am pli er. The current I m easured in this three-term inal arrangem ent therefore solely originates from interedge scattering.

O ne m ay notice in Fig. 1 that the outer edge states are shown going underneath gates B and C. This is because these gates are only partially depleted, but depleted enough so that the electron density beneath the gate is such that only one LL is lled (1), and the inner (spin up) edge state is rejected. The region of 2DEG between the split-gates must also reject the inner edge state, which can be accomplished by increasing the voltage on gate A (V_A) to partially deplete the 2DEG to

1 throughout this region. The reasons for using this sem i-depletion m ethod are detailed in Section V I.

A schematic electrochemical energy diagram of the 2DEG edge is shown in Fig. 2, where the bulk of the sample is to the left and the edge is to the right. A com bination of the sam ple's electrostatic con nem ent potential and the electrons' ability (or inability) to screen this potential leads to the slanting stepw ise energy pro le show n [9]. Electrons in the compressible regions can move around to screen the external con nem ent potential, creating the energetically at regions shown. The electron density within each compressible strip falls steadily from left to right. Between the compressible regions, the electron density is xed at integer lling factor, so these incompressible regions cannot screen the con nem ent potential. It should be noted that this picture does not include quantum mechanical electron-electron interactions such as exchange, which com plicate the picture considerably. W e will discuss this complication in Section V.

The energy level diagram in Fig. 2 resembles that of a diode [17], with the spin-split edge states playing the role of the diode's p- and n-doped regions. W hen the outer edge channel is forward biased, as shown in Fig. 2(b), the energy di erence between the partially led states of the inner edge channel and the available empty states of the outer edge channel decreases, and the incom pressible strip between the edge channels becom es narrow er [19]. For sm all forward bias, only a sm all current of thermalelectrons will ow between the edge states, resulting in a small I. Once jejv exceeds the LL energy splitting g _B B, how ever, the incom pressible strip disappears, and a large current of electrons can move freely from the inner to outer edge channels. W e therefore expect a threshold voltage Vt in the I V trace, corresponding to the LL energy splitting. Conversely, for negative bias (Fig. 2(c)), the interedge energy splitting becomes enhanced, and in order to scatter between edge states, electrons must tunnelthrough the incom pressible strip, leading to a sm all I which depends on both the bias V and the width of the tunnel barrier (which is itself a function of V). Because

of the di erent m odes of transport for forward and negative bias, there should be an asym m etry in I. P revious experim ents on transport between large compressible regions [17,19,20] and between spin-degenerate edge channels and large compressible regions [21] have shown this asym m etry.

Since the LLs in the spin diode are of opposite spin, the scattering of an electron from one LL to the other must be accompanied by a spin ip. It is important to note, how ever, that for forw ard bias, electrons do not necessarily have to ip their spins in order to register a current I. They can be excited from the upper LL of the inner edge channel (therm ally, or with help from a high bias) into the empty states in the upper LL of the outer edge channel, and stay in that channel long enough to m ake it through the AC split-gate and disappear into contact 2. However, some of these "hot" electrons in the upper LL relax to the lower LL by ipping their spin, which can be caused either by spin-orbit scattering [15] or by the contact hyper ne interaction between the electron and the Ga and As nuclei [22]. We will be concerned with the e ects of this hyper nem ediated scattering.

III. EXPER IM EN TAL RESULTS AND IN TEPRETATION

The device was fashioned from a G aA s/A IG aA s heterostructure with a 2D EG density $n_s = 2.5 \ 10^{11}$ electrons/cm² and a mobility of $10^6 \ cm^2/V s$. Patterned split-gates of layered C r and Au were evaporated on the surface of the structure, and N i/G e/A u contacts were annealed to make electrical contact with the 2D EG. The device is shown in Fig. 1(b). The current measurem ent setup used a virtual-ground pream pli er in a standard DC con guration, with the device mounted in a dilution refrigerator and cooled to a base temperature of 30 m K.

For all the spin diode experiments, the magnetic eld was set to 7.0 T (= 2) and the AC and AB split-gates were tuned to transmit only the outermost edge state, as shown in Fig. 1(a), so that the measurement probes the scattering between n = 0" and n = 0# Landau levels. A typical I V measurement is plotted in Fig. 3, showing a rapid increase of current in forward bias with a more gradual increase in reverse bias, as predicted by the spin diode model described in Section II. Note that the forward-bias threshold voltage V_t , where I rapidly changes slope, is comparable to, but greater than, the bare spin splitting g $_B B = 0.18 \text{ meV}$. This is much less than the exchange-enhanced spin splitting (a few meV) in the bulk 2D EG .W e will return to this in Section IV.

W e did not observe the complex structure under reverse bias reported by K ane et al. [17], possibly because our device has a di erent geom etry than the interrupted C orbino-style device used in their experim ents. A lso, as we will show in the D iscussion section, the estimated width of the incompressible region in the K ane spin diodes (70 nm) is about ten times larger than ours, and as such could be large enough to exhibit di erent many-body elects than what we observe.

An important observation is that the I \vee curve in Fig. 3 is hysteretic. The direction of the hysteresis is indicated by the arrows. For forward bias, the current is larger sweeping up in bias than when sweeping down, and for negative bias, the current ism ore negative sweeping up towards zero bias than when sweeping down away from zero bias. The size of the hysteresis loop depends on the sweep rate; the sweep shown in Fig. 3 lasted approximately vem inutes. If the sweep is halted at some point in the loop, the current exponentially [23] relaxes to an equilibrium value with a long relaxation time, typically on the order of 30 seconds.

To understand the origin of this hysteresis, we rst note that the equilibration time constant is similar to previously measured nuclear relaxation times for G a and A s in quantum wells [24], indicating that the source of the hysteresis is the in uence of the G aA s nuclear spins upon the 2D E G electron spin energies through the contact hyper ne interaction. The hyper ne H am iltonian is:

$$AI S = \frac{A}{2} (I^{+} S + I S^{+}) + AI_{z}S_{z}$$
(2)

where A is the hyper ne constant, and I and S are the nuclear and electron spins, respectively. The rst term of Eq. 2, consisting of ladder operators, corresponds to the simultaneous ip- op of electron and nuclear spins, and the second term is the hyper ne splitting.

We connect the hysteresis of Fig. 3 to the hyper ne interaction as follows. In our experiments a steady inux of spin-polarized electrons enters through the AB split-gate, dynam ically polarizing the nuclei in the scattering region through ip- op scattering. The form ation of a nuclear polarization $hI_z i$ in turn a ects the electron energies through the Zeem an-like term $AhI_z iS_z$, which acts like an electric magnetic eld $B_{eff} = hI_z i=g_B$ (0 verhauser electron. This extra eld changes the LL energy splitting to $g_B (B + B_{eff})$, which in turn shifts the threshold voltage V_t . Let us consider that the voltage V begins at large negative bias (lower left-hand corner of Fig. 3). Here the current ow is from outer to inner edge states, which involves a spin ip of up to down. This spin

ip, through the hyper ne interaction, " ops" a nucleus from "down" to "up" [25], so a steady current ow results in a net spin-up nuclear polarization (positive hI_z i). When V is swept up to positive values, the spin diode is in forward bias, so that a large current will begin to ow from inner to outer edge states once V reaches the threshold voltage V_t . This threshold, how ever, is not just the bare spin splitting g $_B$ B; hI_z i is still nonzero because of the slow nuclear polarization decay rate, and it creates a

negative B_{eff} (g = -0.44). Therefore, V_t is low ered and I is increased, compared to the case of unpolarized nuclei. C ontinuing the sweep, at large positive bias the current is from inner to outer edge states, which can involve a spin

ip from down to up. This " ops" a nucleus from "up" to "down," so a steady current ow in this case pumps the nuclei towards a net spin-down nuclear polarization (negative hI_z i). A negative hI_z i creates a positive B_{eff} , which increases V_t and decreases I. This accounts for the lower branch of the hysteresis loop for forward bias in Fig. 3. To nish the sweep, V goes back to negative values, the current ow pumps the nuclei back to a spin-up polarization, and the cycle repeats.

The important point of this model is that the current induces a nuclear polarization through the ip- op term of Eq. 2, and is in turn a ected by the already-existing nuclear polarization through the Zeem an term of Eq. 2. The complex interplay between the two e ects, combined with the long relaxation times for G a and A s nuclei, leads to the observed hysteresis.

It would be useful to observe these hyper ne e ects independently of each other by measuring the I $\,$ V prole of the spin diode at a constant hI_zi . To do this, we perform ed experiments where we held V at a xed value $V_{dw\,ell}$ for 60 seconds-long enough for hI_zi to reach equilibrium then quickly ramped V to a voltage, measured I at that voltage, and immediately returned to $V_{dw\,ell}$ to reset the nuclear polarization. This small duty cycle procedure, repeated form any values of V, keeps the system in a state of constant nuclear polarization, while measuring the I $\,$ V pro le at this xed polarization. Sim ilar experiments were carried out by K ane et al. [17].

Three examples of these measurements, for $V_{dw ell}$ = + 1, 0, and -1 m V, are shown in Fig. 4. A coording to the model, these I V's should correspond to an enhancement, no e ect, and a decrease in the electron spin splitting, respectively. This is indeed what is observed, seeing that V_t is shifted by a signi cant amount between traces. $For V_{dwell} = 0 m V$, we believe the nuclei rem ain unpolarized, and the threshold V_t 0.27 m V. This suggests that g is slightly enhanced (g* 1:5g), yet stillm uch sm aller than has been measured in bulk 2DEGs [26], where g can be as large as 20g. We interpret the shift V $_{\rm t}$ between dwellplots as being the Overhauser shift. For both $V_{dw ell} = +1 V$ and -1 V, $ej V_t j = A hI_z iS_z = 0.10 m eV$, corresponding to an e ective O verhauser eld of about 4 T. The maximum Overhauser eld for GaAs [24] is 5.3 T, so the nuclear spins in the scattering region must be highly polarized (about 85%).

To dem onstrate further that I is indeed a ected by the state of the nuclear spins, we perform ed a series of nuclear m agnetic resonance (NMR) experiments with the spin diode. We mounted a simple one-turn coil next to our sample, to which we applied a frequency-tunable AC voltage in order to produce an AC m agnetic eld perpendicular to B (ie., in the plane of the 2DEG). The spin diode was held at forward bias $V_{dw\,ell} > V_t$, polarizing the nuclei in the scattering region. Fig. 5 displays I as a function of coil frequency near the ⁷⁵As resonance, for three slightly di erent values of B. For all measurements, the frequency was swept from low to high values. Each trace shows a well-de ned peak in current, with the peak shifting to higher frequencies for increasing B.

The peaks are due to NMR absorption; m atching the in-plane AC magnetic eld frequency to the NMR absorption energy for a nuclear species partially erases the polarization of that species, decreasing the O verhauser shift (and V_t) and leading to a sudden increase in current. The peak is located at the expected NMR frequency for 75 As, and scales appropriately with B.Sim ilar behavior was seen for the 69 Ga and 71 Ga absorption lines [28]. K ane et al. [17] reported sim ilar NMR results in their spin diode experiments.

The long exponential tail on the right side of the peaks for B = 7.05 and 7.1 T is due to the long equilibration time, which was comparable to the frequency sweeping rate in these measurements. The B = 7.0 T peak was swept much more slow ly, so that the nuclei were always close to equilibrium during the sweep, as evidenced by the disappearance of the long tail. When the AC frequency is swept very slow ly, the widths of the NMR features are approximately 20 K Hz. This is on the order of the K night shift expected for the electron density of our 2D EG [29], and we will discuss this further in the next Section.

We carried out a series of sim ilar diode-like experiments at = 4, measuring scattering between spindegenerate orbital LL edge states. In those experiments, we observed asymmetric I V curves with a threshold voltage V_t comparable to the cyclotron energy $!_c = eB = m *$. M ore details about these experiments are published elsewhere [30].

IV . D ISC U SSIO N

We rst note that, although our simple model of the spin-split edge explains the electron transport data rather well, it does not include the well-docum ented e ects of exchange, which have been observed [26] to greatly increase the spin gap in bulk 2DEGs near = 1. These e ects have been predicted to manifest them selves at the edge as well, particularly in the neighborhood of the

= 1 incom pressible strip. One theory of the spin-split edge [31] predicts that the spin gap in this region can be enhanced by as much as a factor of 50. Our measurem ents of this gap (through the threshold voltage V_t) appear to indicate otherw ise the spin gap is only slightly enhanced (g* 1:5g)-but this conclusion is based upon the assumption that V_t and g* $_B$ B are directly related.

To estim ate the various pertinent length scales, we applied the self-consistent electrostatic model of C hk lovskii et al. [9] to spin-split edge states, substituting the bare

spin gap g $_{\rm B}$ B for h! c. In this case, the = 1 incom – pressible strip is centered at about 70 nm from the edge of the 2D EG, with a width of about 7 nm, com parable to the magnetic length (10 nm). At length scales this small, the local density approximation fails, so it is reasonable to expect that exchange calculations for bulk samples cannot be applied directly to such a small edge region. M ore sophisticated theories of the physics of spin-split edge states do exist, and we discuss their relevance to our experiments as follows.

O ne theory [31] of spin-split edge states predicts hysteresis due entirely to electron-electron interactions. At a critical potential in balance $c_{\rm cr}^+$, the edge channels are predicted to switch positions, remaining in this switched orientation until a di erent potential di erence $c_{\rm cr}$ is reached. We believe, how ever, that our DNP interpretation explains the observed hysteresis adequately, and we see no compelling evidence of this channel-crossing phenom enon. A nother theory [12] predicts that, for certain ranges of the depletion width w (normalized to w = w =) and Zeem an strength $g = g_{\rm B} = (e^2 - e)$, the 2D EG edge supports spin deform ations running along the edge (for

< 1). W e estim ate our device's param eters to be w 7 0:016, placing it within the parameter space and g where these spin-textured edges are predicted to exist. This textured edge theory, however, makes no predictions about the transport properties of such a system, so we cannot con m the existence of such a texture in our experim ent. W e know of no theory which speci cally predicts the current ow between spin-split edges as a function of the non-linear potential di erence between them . Such a theory would require careful exam ination of m any di erent facets of the problem : self-consistent electrostatics, exchange interactions, potential in balances, electrodynamic e ects due to interedge current ow, and, as we discuss below, hyper ne interactions.

It is clear from the dwell plots in Fig. 4 that a net nuclear polarization creates a large O verhauser shift of the edge state energies, so we believe that a com plete description of the physics of the 2DEG edge cannot ignore hyper ne e ects. W hile it is true that edge state transport experiments in the linear regime (ie. $ieV j < g_B B$) will not create a nuclear polarization, it is clear from our experim ents that non-linear transport between spinsplit edges can create one, so it is in portant to consider hyper ne e ects in this regime. The many-body e ects predicted by theory could very well be a ected by the nuclear polarization, adding yet another com plication to the spin-split 2DEG edge model. A lthough the inclusion of the hyper ne interaction appears to just com plicate an already complicated model, it might actually be useful as a tool for m easuring the spatial electron spin variation.

As we have shown, the O verhauser shift can provide information about the local nuclear polarization, so it seems possible that the K night shift can likewise be used as a probe of the spatially varying electron spin density near the edge. At = 2 the bulk of the 2D EG produces no K night shift, since the net electron spin is zero. Near the edge, how ever, there will be a region (the incom pressible strip) of only one spin species, fringed by regions of unbalanced spin m ixtures. These regions of 2D EG would produce K night shifts due to their net electron spin. The sum m ation of the K night shifts from di erent regions of spin density should produce overstructure on the NM R absorption peaks. Som e of our data (not shown) show asym m etric NM R peaks with a slight bump on the left side, where a K night-shifted peak would be expected to appear. U nfortunately, due to the sw itching noise of our sam ple, we were unable to accurately m easure this overstructure, but we plan to pursue this m ethod in the near future.

V.COM PAR ISON W ITH OUR EARLIER EXPERIMENTS

The experiments outlined in this paper are continuations of previous work by our group [18] examining DNP e ects using a similar experimental set-up [32]. In this section, we review those previous results, noting that the observed hysteresis di ered in important ways from the results reported in Section III. We then discuss the origin of the di erences between the two experiments. We show that the voltages on the gates must be carefully chosen if they are to properly inject and detect the spinpolarized edge currents. In the experiments of R ef. [18], this was not done, leading to what we now believe is an incorrect interpretation of the relative in portance of the

ip- op and Zeem an term s in the experiments. In particular, the hysteresis in Ref. [18] was attributed entirely to the e ects of ip- op scattering, while we now feel that the in uence of the nuclear Zeem an term was crucial to understand the experiments.

In the experiments of Ref. [18], the I V curves displayed symmetric hysteresis. By this we mean that jIjwas greater when V was being swept away from zero than it was when being swept toward zero, for both positive and negative V. In other words, starting from the origin and sweeping V from zero to (say) + 1 m V to -1 m V to zero, the absolute current values were, in sequence: high, low, high, low. We explained this hysteresis by considering the currents carried by ip- op scattered electrons. W henever the voltage changes sign, inter-edge scattering increases due to ip- op scattering with the residual nuclear polarization, leading to an increased jIj. We refer the reader to Ref. [18] for a detailed explanation.

In our more recent measurements (e.g. Fig. 3), the hysteresis was observed to be antisymmetric. I is enhanced when sweeping V away from zero for positive V (because the spin gap is smaller due to the spin-up polarization), but suppressed for negative V (because the spin

gap is larger due to the spin-down polarization). The hysteresis sweeps out a gure-8 (antisymm etric) rather than a pinched loop (symmetric). This asymmetric hysteresis is most naturally interpreted in terms of the nuclear Zeem an elect, as discussed in Section III.

W hy is the hysteresis symmetry dierent? The answer lies in the gate voltages applied to the QPCs that were used to inject polarized electrons into the scattering region. We observed antisymmetric hysteresis when we only partially depleted gates B and C, as shown in Fig. 1(a). Upon increasing the voltage on these gates so that they became fully-depleted, the hysteresis became symmetric. In the experiments of Ref. [18], fully depleted QPCs were used, resulting in symmetric hysteresis.

This observation led us to exam ine the AB split-gate by itself, in various states of depletion, to try to understand what was causing this hysteresis change. Figure 6 shows the di erential conductance through the AB split-gate as a function of V for various values of V_B, with V_A held at -1 V. For V_B > -0.35 V, the conductance is a fairly at e²=h, with some deviation at large negative V.Form ore negative values of V_B, however, the conductance deviates drastically from e²=h for jV j > 0.4 mV. The value of the gate voltage V_B at which this transition occurs is at the voltage at which the electron gas becomes fully depleted under the gate itself.

C onsider the paths of the edge channels near the AB split-gate, diagram m ed in Figure 7. The edge channels entering the split-gate from above are populated to the potential = eV while the edge channels entering from the bottom are at zero potential. If the AB split-gate forms a fully depleted QPC, the incoming and outgoing outer edge channels pass very close to each other while making their way between the gates, as shown in Figure 7(a). If the bias V is high, a large electric eld will exist within the QPC, which could cause the electrostatic potential pro le near the constriction to be deform ed and cause unintended scattering and edge-state mixing (dotted lines). For a partially depleted QPC, shown in 7(b), the edge states are very far apart, and little scattering is expected to occur.

W e therefore conclude that that the electrons transm itted through a fully-depleted QPC (Fig. 7(a)) at high biasses exhibit signi cant inter-channel scattering and thus are (a) not spin-polarized and (b) not populated up to the electrochem ical potential m at which they entered the QPC. On the other hand, for a partially depleted QPC (Fig 7(b)), the edge channels of di erent potentials rem ain m acroscopically apart from each other, preserving the non-equilibrium current distribution even at large nonlinear biases. As a result, the m easurem ents and interpretaions reported in section III, using partially depleted QPC s, are m ore reliable than those given in R ef. [18], where fully depleted QPC s were employed.

A lthough we have show n that a fullQPC displays com plex behavior under high bias, the connection between this behavior and the change in the hysteresis loop remains poorly understood. This is because the detailed behavior of the individual QPCs in this limit is not known; more experimental and theoretical work is required. It should be possible to empirically measure the scattering matrix of such a QPC as a function of V and the gate voltages, but we have not made an attempt to do so. Further, theoretical models of QPCs under high bias that takes into account the distortion of the electrostatic potential prolementioned above should be developed.

VI.CONCLUSIONS

We have observed I V asymmetry in scattering between spin-polarized edge states, and detected remarkably strong e ects of GaAs nuclear spins upon these I V traces. For forward bias, the I V trace displays a threshold which is nearly the bare Zeem an splitting, and for reverse bias the current increases only gradually with no apparent threshold. We also observed hysteresis in these traces, which we interpret as being due to a combination of the dynam ic nuclear polarization of the nearby nuclei and the hyper ne in uence of the nuclear polarization on the electron energies. The strength of the Overhauser eld created by the polarized nucleiwas found to be nearly as large as the external eld itself. The evidence for nuclear in uence was supported by a series of NMR sweeps, which demonstrated that NMR absorption a ected the current ow through the device. From these experiments, we conclude that it is critical to consider the hyper ne interaction between G a and A s nuclei and the 2DEG in these systems, and that these interactions may be useful as a local probe of the edge.

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FIG.1. (a) Schem atic of device geom etry for lling factor = 2. Electrons of both spins enter from contact 1 at a bias V. Only the spin-up edge channel is transmitted through gates A and B, and the electrons in this edge channel enter the scattering region where they can scatter into the grounded spin-down edge channel. Scattered electrons then proceed to the current ampli er attached to contact 3 (lower right) and are m easured as current I. Unscattered electrons disappear into the grounded contact 2 (upper right) and avoid detection. (b) AFM im age of the device, with a 1 m m bar provided as a reference. The bottom gate was not used in these experim ents, so it was grounded.

FIG.2. Landau level energy diagram near the edge of a 2D EG, for no bias (a), forward bias (b), and reverse bias (c). The electron energies atten out at the Ferm ienergy E $_{\rm F}$ due to self-consistent electrostatic screening, forming compressible strips (at regions, gray dots) and incompressible strips (sloped regions, black dots). In forward bias (b), very little current ow s unless eV exceeds g $_{\rm B}$ B, whereupon electrons can move readily from the inner to the outer edge channel. In reverse bias (c), the current consists only of electrons that tunnel through the incom pressible strip from the outer to the inner edge channel.

FIG.3. Spin diode I V. For forward bias, the current is smalluntil eV reaches a threshold voltage comparable to the bare spin splitting g $_{\rm B}$ B = 0.175 meV. In reverse bias, the current gradually increases with no apparent threshold. The trace also displays hysteresis, with the V sweep direction indicated by the arrows. The two insets schem atically show the ip- op scattering between electron spins and nuclear spins for negative and positive bias. The nuclear polarization is schem atically shown for each step of the hysteresis loop, as discussed in the text.

FIG.4. I V traces taken at constant nuclear polarization. For each trace, the nuclei were prepared by dwelling at a speci ed voltage V_{dw ell} for 60 seconds, then quickly changing the voltage to another value, m easuring I, and returning to V_{dw ell} to m aintain the polarization. For V_{dw ell} = -1 m V, the nuclear polarization was up, and for V_{dw ell} = +1 m V, the polarization was down. The threshold voltage is shifted by the 0 verhauser e ect of the prepared nuclear polarization on the electrons.

FIG.5. NMR absorption peaks, showing a marked change in current when the frequency of an in-plane AC magnetic eld matches the splitting of a nuclear species (in this case, 75 As). The peaks shift linearly with B.Allplots were taken sweeping frequency from left to right. The B = 7.0 T peak was swept at a much slower rate than the other two peaks, which have asymmetric lineshapes because the sweeping rate was comparable to the equilibration rate of nuclear repolarization.

FIG.6. Plots of the di erential conductance through the AB split-gate as a function of V for various values of $V_{\rm B}$. The bulk lling factor = 2, and $V_{\rm A}$ = -1 V.W hen gate B is only partially depleted (e.g. $V_{\rm B}$ = -0.35 V), but still transmitting only one edge state, the conductance is basically at at e^2 =h, with a slight rise at nonlinear biases. W hen gate B is depleted ($V_{\rm B}$ < -0.35 V), the conductance deviates dram atically from e^2 =h.

FIG.7. Schem atic of full and sem iQPCs, with the edge states owing in the directions indicated by the arrows, and labeled by their electrochem ical potentials. In (a), both arms of the QPC are fully depleted. The incoming and outgoing edge channels are forced to run close to each other inside the QPC, so if there is a large di erence in their potentials, a large electric eld exists within the QPC, which would distort the potential pro le and cause unintended scattering and edge state mixing (dotted arrows). In (b), gate B is partially depleted, but still only transmits one edge state, and the inner edge state is prevented from leaking through the region between the split-gates by a large V_A . The incoming and outgoing edge channels are now far apart, preventing the scattering problem s in (a).

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